

**DESCRIPTION**

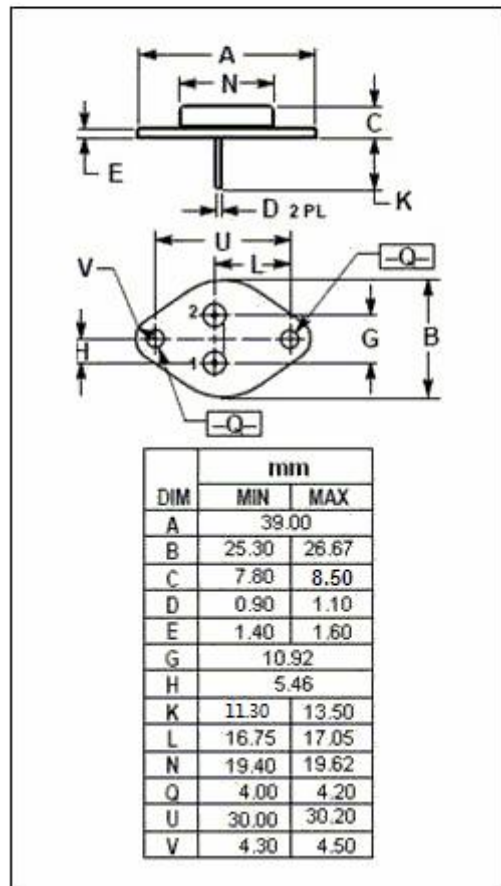
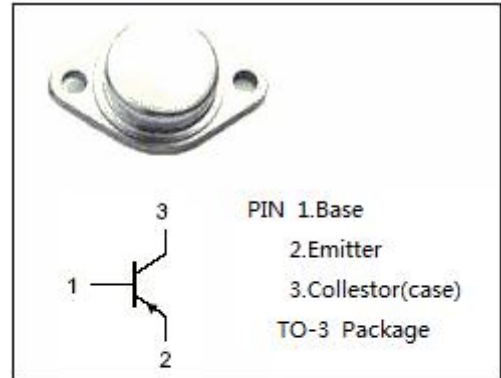
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = -140V(\text{Min})$
- High Power Dissipation-  
:  $P_C = 80W(\text{Max})@T_C=25^\circ\text{C}$
- Complement to Type 2SD425

**APPLICATIONS**

- Designed for power amplifier applications.
- Recommended for 80W high-fidelity audio frequency amplifier output stage.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-140	V
$V_{CEO}$	Collector-Emitter Voltage	-140	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current-Continuous	-12	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	80	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-65~150	$^\circ\text{C}$



**ELECTRICAL CHARACTERISTICS**

T<sub>j</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-140			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -10mA; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -0.7A			-3.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -7A; V <sub>CE</sub> = -5V			-2.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -60V; I <sub>E</sub> = 0			-0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-0.1	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -2A; V <sub>CE</sub> = -5V	40		140	
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f= 1MHz		330		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = -2A; V <sub>CE</sub> = -5V		6		MHz

◆ **h<sub>FE</sub> Classifications**

R	O
40-80	70-140